SSTUH32866

1.8 V high output drive 25-bit 1 : 1 or 14-bit 1 : 2 configurable registered buffer with parity for DDR2 RDIMM applications

Rev. 01 — 13 May 2005

Product data sheet



The SSTUH32866 is a 1.8 V configurable register specifically designed for use on DDR2 memory modules requiring a parity checking function. It is defined in accordance with the JEDEC JESD82-7 standard for the SSTU32864 registered buffer, while adding the parity checking function in a compatible pinout. The JEDEC standard for SSTUH32866 is pending publication. The register is configurable (using configuration pins C0 and C1) to two topologies: 25-bit 1: 1 or 14-bit 1: 2, and in the latter configuration can be designated as Register A or Register B on the DIMM.

The SSTUH32866 accepts a parity bit from the memory controller on its parity bit (PAR_IN) input, compares it with the data received on the DIMM-independent D-inputs and indicates whether a parity error has occurred on its open-drain QERR pin (active LOW). The convention is even parity, that is, valid parity is defined as an even number of ones across the DIMM-independent data inputs combined with the parity input bit.

The SSTUH32866 is packaged in a 96-ball, 6×16 grid, 0.8 mm ball pitch LFBGA package (13.5 mm \times 5.5 mm).

The SSTUH32866 is identical to SSTU32866 in function and performance, with higher-drive outputs optimized to drive heavy load nets (for example, stacked DRAMs) while maintaining speed and signal integrity.

2. Features

- Configurable register supporting DDR2 Registered DIMM applications
- Higher output drive strength version of SSTU32866 optimized for high-capacitive load nets
- Configurable to 25-bit 1 : 1 mode or 14-bit 1 : 2 mode
- Controlled output impedance drivers enable optimal signal integrity and speed
- Exceeds JESD82-7 speed performance (1.8 ns max. single-bit switching propagation delay; 2.0 ns max. mass-switching)
- Supports up to 450 MHz clock frequency of operation
- Optimized pinout for high-density DDR2 module design
- Chip-selects minimize power consumption by gating data outputs from changing state
- Supports SSTL_18 data inputs
- Checks parity on the DIMM-independent data inputs
- Partial parity output and input allows cascading of two SSTUH32866s for correct parity error processing
- Differential clock (CK and CK) inputs



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- Supports LVCMOS switching levels on the control and RESET inputs
- Single 1.8 V supply operation
- Available in 96-ball, 13.5 mm × 5.5 mm, 0.8 mm ball pitch LFBGA package

3. Applications

- DDR2 registered DIMMs desiring parity checking functionality
- Stacked or planar high-DRAM count registered DIMMs

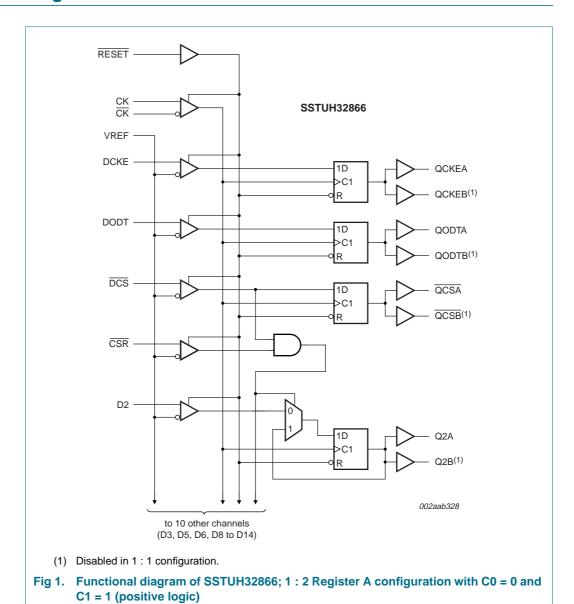
4. Ordering information

Table 1: Ordering information

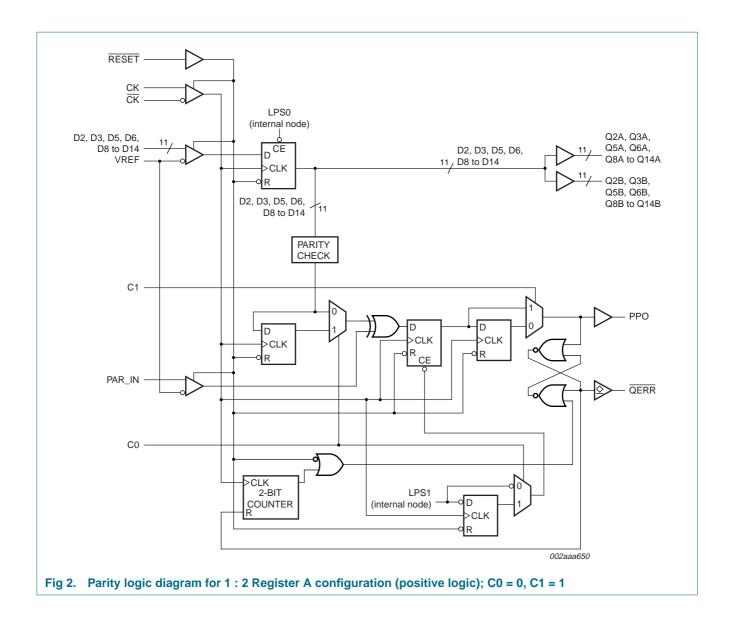
 $T_{amb} = 0 \,^{\circ}C$ to +70 $^{\circ}C$.

Type number	Solder process	Package		
		Name	Description	Version
SSTUH32866EC/G	Pb-free (SnAgCu solder ball compound)	LFBGA96	plastic low profile fine-pitch ball grid array package; 96 balls; body $13.5 \times 5.5 \times 1.05$ mm	SOT536-1
SSTUH32866EC	SnPb solder ball compound	LFBGA96	plastic low profile fine-pitch ball grid array package; 96 balls; body 13.5 \times 5.5 \times 1.05 mm	SOT536-1

5. Functional diagram

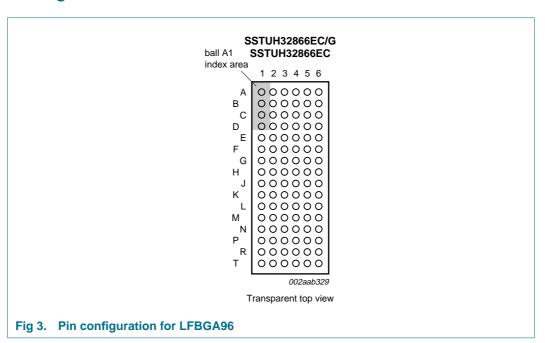


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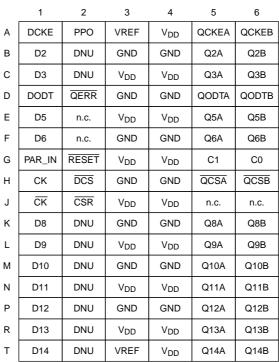
6. Pinning information

6.1 Pinning



	1	2	3	4	5	6
А	DCKE	PPO	VREF	V_{DD}	QCKE	DNU
В	D2	D15	GND	GND	Q2	Q15
С	D3	D16	V_{DD}	V _{DD}	Q3	Q16
D	DODT	QERR	GND	GND	QODT	DNU
E	D5	D17	V_{DD}	V _{DD}	Q5	Q17
F	D6	D18	GND	GND	Q6	Q18
G	PAR_IN	RESET	V _{DD}	V _{DD}	C1	C0
Н	СК	DCS	GND	GND	QCS	DNU
J	СK	CSR	V_{DD}	V _{DD}	n.c.	n.c.
K	D8	D19	GND	GND	Q8	Q19
L	D9	D20	V_{DD}	V_{DD}	Q9	Q20
M	D10	D21	GND	GND	Q10	Q21
N	D11	D22	V_{DD}	V_{DD}	Q11	Q22
Р	D12	D23	GND	GND	Q12	Q23
R	D13	D24	V_{DD}	V _{DD}	Q13	Q24
Т	D14	D25	VREF	V _{DD}	Q14	Q25
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Fig 4. Ball mapping, 1:1 register (C0 = 0, C1 = 0)



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Fig 5. Ball mapping, 1 : 2 Register A (C0 = 0, C1 = 1)

1	2	3	4	5	6
D1	PPO	VREF	V_{DD}	Q1A	Q1B
D2	DNU	GND	GND	Q2A	Q2B
D3	DNU	V _{DD}	V _{DD}	Q3A	Q3B
D4	QERR	GND	GND	Q4A	Q4B
D5	DNU	V _{DD}	V _{DD}	Q5A	Q5B
D6	DNU	GND	GND	Q6A	Q6B
PAR_IN	RESET	V _{DD}	V _{DD}	C1	C0
СК	DCS	GND	GND	QCSA	QCSB
CK	CSR	V _{DD}	V _{DD}	n.c.	n.c.
D8	DNU	GND	GND	Q8A	Q8B
D9	DNU	V _{DD}	V _{DD}	Q9A	Q9B
D10	DNU	GND	GND	Q10A	Q10B
DODT	DNU	V_{DD}	V _{DD}	QODTA	QODTB
D12	DNU	GND	GND	Q12A	Q12B
D13	DNU	V _{DD}	V _{DD}	Q13A	Q13B
DCKE	DNU	VREF	V _{DD}	QCKEA	QCKEB
	D1 D2 D3 D4 D5 D6 PAR_IN CK D8 D9 D10 DODT D12 D13	D1 PPO D2 DNU D3 DNU D4 QERR D5 DNU D6 DNU PAR_IN RESET CK DCS CK CSR D8 DNU D9 DNU D10 DNU DODT DNU D12 DNU D13 DNU	D1 PPO VREF D2 DNU GND D3 DNU VDD D4 QERR GND D5 DNU VDD D6 DNU GND PAR_IN RESET VDD CK DCS GND CK CSR VDD D8 DNU GND D9 DNU VDD D10 DNU GND DODT DNU GND D12 DNU GND D13 DNU VDD	D1 PPO VREF VDD D2 DNU GND GND D3 DNU VDD VDD D4 QERR GND GND D5 DNU VDD VDD D6 DNU GND GND PAR_IN RESET VDD VDD CK DCS GND GND D8 DNU GND GND D9 DNU GND GND D0D DNU GND GND D0DT DNU VDD VDD D12 DNU GND GND D13 DNU VDD VDD	D1 PPO VREF VDD Q1A D2 DNU GND GND Q2A D3 DNU VDD VDD Q3A D4 QERR GND GND Q4A D5 DNU VDD VDD Q5A D6 DNU GND GND Q6A PAR_IN RESET VDD VDD C1 CK DCS GND GND QCSA CK CSR VDD VDD n.c. D8 DNU GND GND Q8A D9 DNU VDD VDD Q9A D10 DNU GND GND Q10A DODT DNU VDD VDD Q0DTA D12 DNU GND GND Q13A

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Fig 6. Ball mapping, 1 : 2 Register B (C0 = 1, C1 = 1)

6.2 Pin description

Table 2: Pin description

Symbol	Pin	Туре	Description
GND	B3, B4, D3, D4, F3, F4, H3, H4, K3, K4, M3, M4, P3, P4	ground input	ground
V_{DD}	A4, C3, C4, E3, E4, G3, G4, J3, J4, L3, L4, N3, N4, R3, R4, T4	1.8 V nominal	power supply voltage
VREF	A3, T3	0.9 V nominal	input reference voltage
CK	H1	Differential input	positive master clock input
CK	J1	Differential input	negative master clock input
C0 C1	G6 G5	LVCMOS inputs	Configuration control inputs; Register A or Register B and 1 : 1 mode or 1 : 2 mode select.
RESET	G2	LVCMOS input	Asynchronous reset input (active LOW). Resets registers and disables VREF data and clock.
CSR	J2	SSTL_18 input	Chip select inputs (active LOW). Disables
DCS	H2		D1 to D25 2 outputs switching when both inputs are HIGH.
D1 to D25	[1]	SSTL_18 input	Data input. Clocked in on the crossing of the rising edge of CK and the falling edge of $\overline{\text{CK}}$.
DODT	<u>[1]</u>	SSTL_18 input	The outputs of this register bit will not be suspended by the \overline{DCS} and \overline{CSR} control.
DCKE	<u>[1]</u>	SSTL_18 input	The outputs of this register bit will not be suspended by the \overline{DCS} and \overline{CSR} control.
PAR_IN	G1	SSTL_18 input	Parity input. Arrives one clock cycle after the corresponding data input.
Q1 to Q25, Q2A to Q14A, Q1B to Q14B	[1]	1.8 V CMOS outputs	Data outputs that are suspended by the DCS and CSR control 3.
PPO	A2	1.8 V CMOS output	Partial parity out. Indicates odd parity of inputs D1 to D25 [2].
$\overline{\text{QCS}}$, $\overline{\text{QCSA}}$, $\overline{\text{QCSB}}$	<u>[1]</u>	1.8 V CMOS output	Data output that will not be suspended by the DCS and CSR control.
QODT, QODTA, QODTB	<u>[1]</u>	1.8 V CMOS output	Data output that will not be suspended by the DCS and CSR control.
QCKE, QCKEA, QCKEB	<u>[1]</u>	1.8 V CMOS output	Data output that will not be suspended by the DCS and CSR control.

Table 2: Pin description ...continued

Symbol	Pin	Туре	Description
QERR	D2	open-drain output	Output error bit (active LOW). Generated one clock cycle after the corresponding data output
n.c.	<u>[1]</u>	-	Not connected. Ball present but no internal connection to the die.
DNU	<u>[1]</u>	-	Do not use. Inputs are in standby-equivalent mode and outputs are driven LOW.

- [1] Depends on configuration. See Figure 4, Figure 5, and Figure 6 for ball number.
- [2] Data inputs = D2, D3, D5, D6, D8 to D25 when C0 = 0 and C1 = 0.
 Data inputs = D2, D3, D5, D6, D8 to D14 when C0 = 0 and C1 = 1.
 Data inputs = D1 to D6, D8 to D10, D12, D13 when C0 = 1 and C1 = 1.
- [3] Data outputs = Q2, Q3, Q5, Q6, Q8 to Q25 when C0 = 0 and C1 = 0.
 Data outputs = Q2, Q3, Q5, Q6, Q8 to Q14 when C0 = 0 and C1 = 1.
 Data outputs = Q1 to Q6, Q8 to Q10, Q12, Q13 when C0 = 1 and C1 = 1.

7. Functional description

The SSTUH32866 is a 25-bit 1 : 1 or 14-bit 1 : 2 configurable registered buffer with parity, designed for 1.7 V to 1.9 V V_{DD} operation.

All clock and data inputs are compatible with the JEDEC standard for SSTL_18. The control and reset (RESET) inputs are LVCMOS. All data outputs are 1.8 V CMOS drivers that have been optimized to drive the DDR2 DIMM load, and meet SSTL_18 specifications. The error (QERR) output is 1.8 V open-drain driver.

The SSTUH32866 operates from a differential clock (CK and $\overline{\text{CK}}$). Data are registered at the crossing of CK going HIGH, and CK going LOW.

The C0 input controls the pinout configuration for the 1 : 2 pinout from A configuration (when LOW) to B configuration (when HIGH). The C1 input controls the pinout configuration from 25-bit 1 : 1 (when LOW) to 14-bit 1 : 2 (when HIGH).

The SSTUH32866 accepts a parity bit from the memory controller on its parity bit (PAR_IN) input, compares it with the data received on the DIMM-independent D-inputs and indicates whether a parity error has occurred on its open-drain QERR pin (active LOW). The convention is even parity, that is, valid parity is defined as an even number of ones across the DIMM-independent data inputs combined with the parity input bit.

When used as a single device, the C0 and C1 inputs are tied LOW. In this configuration, parity is checked on the PAR_IN input which arrives one cycle after the input data to which it applies. The partial-parity-out (PPO) and $\overline{\text{QERR}}$ signals are produced three cycles after the corresponding data inputs.

When used in pairs, the C0 input of the first register is tied LOW and the C0 input of the second register is tied HIGH. The C1 input of both registers are tied HIGH. Parity, which arrives one cycle after the data input to which it applies, is checked on the PAR_IN input of the first device. The PPO and QERR signals are produced on the second device three clock cycles after the corresponding data inputs. The PPO output of the first register is

cascaded to the PAR_IN of the second register. The $\overline{\text{QERR}}$ output of the first register is left floating and the valid error information is latched on the $\overline{\text{QERR}}$ output of the second register.

If an error occurs and the $\overline{\text{QERR}}$ output is driven LOW, it stays latched LOW for two clock cycles or until $\overline{\text{RESET}}$ is driven LOW. The DIMM-dependent signals (DCKE, $\overline{\text{DCS}}$, DODT, and $\overline{\text{CSR}}$) are not included in the parity check computation.

The device supports low-power standby operation. When RESET is LOW, the differential input receivers are disabled, and undriven (floating) data, clock and reference voltage (VREF) inputs are allowed. In addition, when RESET is LOW all registers are reset, and all outputs are forced LOW. The LVCMOS RESET input must always be held at a valid logic HIGH or LOW level.

The device also supports low-power active operation by monitoring both system chip select (\overline{DCS} and \overline{CSR}) inputs and will gate the Qn and PPO outputs from changing states when both \overline{DCS} and \overline{CSR} inputs are HIGH. If either \overline{DCS} or \overline{CSR} input is LOW, the Qn and PPO outputs will function normally. The \overline{RESET} input has priority over the \overline{DCS} and \overline{CSR} control and when driven LOW will force the Qn and PPO outputs LOW, and the \overline{QERR} output HIGH. If the \overline{DCS} control functionality is not desired, then the \overline{CSR} input can be hard-wired to ground, in which case, the setup time requirement for \overline{DCS} would be the same as for the other Dn data inputs. To control the low-power mode with \overline{DCS} only, then the \overline{CSR} input should be pulled up to V_{DD} through a pull-up resistor.

To ensure defined outputs from the register before a stable clock has been supplied, RESET must be held in the LOW state during power-up.

In the DDR2 RDIMM application, $\overline{\text{RESET}}$ is specified to be completely asynchronous with respect to CK and $\overline{\text{CK}}$. Therefore, no timing relationship can be guaranteed between the two. When entering reset, the register will be cleared and the Qn outputs will be driven LOW quickly, relative to the time to disable the differential input receivers. However, when coming out of reset, the register will become active quickly, relative to the time to enable the differential input receivers. As long as the data inputs are LOW, and the clock is stable during the time from the LOW-to-HIGH transition of $\overline{\text{RESET}}$ until the input receivers are fully enabled, the design of the SSTUH32866 must ensure that the outputs will remain LOW, thus ensuring no glitches on the output.

7.1 Function table

Table 3: Function table (each flip-flop)

L = LOW voltage level: H = HIGH voltage level: X = don't care: $\uparrow = LOW$ -to-HIGH transition: $\downarrow = HIGH$ -to-LOW transition

		In	puts				Outputs [1]	
RESET	DCS	CSR	СК	CK	Dn, DODTn, DCKEn	Qn	QCS	QODT, QCKE
Н	L	L	1	<u> </u>	L	L	L	L
Н	L	L	1	\downarrow	Н	Н	L	Н
Н	L	L	L or H	L or H	X	Q_0	Q_0	Q_0
Н	L	Н	1	\downarrow	L	L	L	L
Н	L	Н	1	\downarrow	Н	Н	L	Н
Н	L	Н	L or H	L or H	X	Q_0	Q_0	Q_0
Н	Н	L	1	\downarrow	L	L	Н	L
Н	Н	L	1	\downarrow	Н	Н	Н	Н
Н	Н	L	L or H	L or H	X	Q_0	Q_0	Q_0
Н	Н	Н	1	\downarrow	L	Q_0	Н	L
Н	Н	Н	1	\downarrow	Н	Q_0	Н	Н
Н	Н	Н	L or H	L or H	X	Q_0	Q_0	Q_0
L	X or floating	L	L	L				

^[1] Q₀ is the previous state of the associated output.

Table 4: Parity and standby function table

L = LOW voltage level; H = HIGH voltage level; X = don't care; $\uparrow = LOW$ -to-HIGH transition; $\downarrow = HIGH$ -to-LOW transition

	,							. [41
			Inputs				Outp	uts [1]
RESET	DCS	CSR	СК	CK	Σ of inputs = H (D1 to D25)	PAR_IN[2]	PPO [3]	QERR [4]
Н	L	Χ	\uparrow	\downarrow	even	L	L	Н
Н	L	Χ	1	\downarrow	odd	L	Н	L
Н	L	Χ	1	\downarrow	even	Н	Н	L
Н	L	Χ	1	\downarrow	odd	Н	L	Н
Н	Н	L	1	\downarrow	even	L	L	Н
Н	Н	L	1	\downarrow	odd	L	Н	L
Н	Н	L	1	\downarrow	even	Н	Н	L
Н	Н	L	1	\downarrow	odd	Н	L	Н
Н	Н	Н	1	\downarrow	X	Х	PPO ₀	QERR ₀
Н	Х	Х	L or H	L or H	X	Х	PPO_0	QERR ₀
L	X or floating	X or floating	L	Н				

^[1] PPO₀ is the previous state of output PPO; $\overline{\text{QERR}}_0$ is the previous state of output $\overline{\text{QERR}}$.

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 ^[2] Data inputs = D2, D3, D5, D6, D8 to D25 when C0 = 0 and C1 = 0.
 Data inputs = D2, D3, D5, D6, D8 to D14 when C0 = 0 and C1 = 1.
 Data inputs = D1 to D6, D8 to D10, D12, D13 when C0 = 1 and C1 = 1.

^[3] PAR_IN arrives one clock cycle (C0 = 0), or two clock cycles (C0 = 1), after the data to which it applies.

^[4] This condition assumes QERR is HIGH at the crossing of CK going HIGH and CK going LOW. If QERR is LOW, it stays latched LOW for two clock cycles or until RESET is driven LOW.

8. Limiting values

Table 5: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DD}	supply voltage		-0.5	+2.5	V
VI	receiver input voltage		-0.5 [1]	+2.5[2]	V
Vo	driver output voltage		-0.5 [1]	V _{DD} + 0.5 2	V
I _{IK}	input clamp current	$V_I < 0 \text{ V or } V_I > V_{DD}$	-	-50	mA
I _{OK}	output clamp current	$V_O < 0 \text{ V or } V_O > V_{DD}$	-	±50	mA
Io	continuous output current	$0 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{DD}}$	-	±50	mA
I _{CCC}	continuous current through each V _{DD} or GND pin		-	±100	mA
T _{stg}	storage temperature		-65	+150	°C
V _{esd}	electrostatic discharge voltage	Human Body Model (HBM); 1.5 kΩ; 100 pF	2	-	kV
		Machine Model (MM); 0 Ω; 200 pF	200	-	V

^[1] The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

9. Recommended operating conditions

Table 6: Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DD}	supply voltage		1.7	-	1.9	V
V_{ref}	reference voltage		$0.49 \times V_{DD}$	$0.50 \times V_{DD}$	$0.51 \times V_{DD}$	V
V_{TT}	termination voltage		$V_{\text{ref}}-0.040$	V_{ref}	$V_{ref} + 0.040$	V
V_{I}	input voltage		0	-	V_{DD}	V
V _{IH(AC)}	AC HIGH-level input voltage	data (Dn), CSR, and PAR_IN inputs	V _{ref} + 0.250	-	-	V
V _{IL(AC)}	AC LOW-level input voltage	data (Dn), CSR, and PAR_IN inputs	-	-	V _{ref} – 0.250	V
V _{IH(DC)}	DC HIGH-level input voltage	data (Dn), CSR, and PAR_IN inputs	V _{ref} + 0.125	-	-	V
V _{IL(DC)}	DC LOW-level input voltage	data (Dn), CSR, and PAR_IN inputs	-	-	V _{ref} – 0.125	V
V _{IH}	HIGH-level input voltage	RESET, Cn	$[1] 0.65 \times V_{DD}$	-	-	V
V _{IL}	LOW-level input voltage	RESET, Cn	[1] -	-	$0.35 \times V_{DD}$	V
V _{ICR}	common mode input voltage range	CK, CK	[<u>2</u>] 0.675	-	1.125	V
V_{ID}	differential input voltage	CK, CK	[2] 600	-	-	mV

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^[2] This value is limited to 2.5 V maximum.

 Table 6:
 Recommended operating conditions ...continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{OH}	HIGH-level output current		-	-	–12	mA
I _{OL}	LOW-level output current		-	-	12	mA
T _{amb}	ambient temperature	operating in free air	0	-	+70	°C

^[1] The RESET and Cn inputs of the device must be held at valid levels (not floating) to ensure proper device operation.

10. Characteristics

Table 7: Characteristics

At recommended operating conditions (see Table 6), unless otherwise specified.

$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	V_{OH}	HIGH-level output voltage	$I_{OH} = -12 \text{ mA}; V_{DD} = 1.7 \text{ V}$	1.2	-	-	V
$V_{DD} = 1.9 \text{ V}$ I_{DD} I_{DD} I_{DD} I_{DD} I_{DDD}	V _{OL}	LOW-level output voltage	I _{OL} = 12 mA; V _{DD} = 1.7 V	-	-	0.5	V
	I _I	input current		-	-	±5	μΑ
$V_{DD} = 1.9 \text{ V; } V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}$ I_{DDD} $V_{DD} = 1.9 \text{ V; } V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{CK}$ $V_1 = V_{IH(AC)} \text{ or } V_{IL(AC)}$	I _{DD}	static standby current	, ,	-	-	100	μΑ
clock only $ \begin{array}{c} V_I = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{\text{CK}} \\ \text{switching at } 50 \text{ % duty cycle.} \\ I_O = 0 \text{ mA; } V_{DD} = 1.8 \text{ V} \\ \\ \hline \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ $		static operating current	22, 0	-	-	40	mA
per each data input, 1 : 1 mode $V_{I} = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{\text{CK}} \\ \text{switching at 50 \% duty cycle. One} \\ \text{data input switching at half clock} \\ \text{frequency, 50 \% duty cycle.} \\ I_{O} = 0 \text{ mA; } V_{DD} = 1.8 \text{ V} \\ \hline \text{dynamic operating current per MHz,} \\ \text{per each data input, 1 : 2 mode} \\ \hline V_{I} = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{\text{CK}} \\ \text{switching at 50 \% duty cycle. One} \\ \text{data input switching at half clock} \\ \text{frequency, 50 \% duty cycle.} \\ I_{O} = 0 \text{ mA; } V_{DD} = 1.8 \text{ V} \\ \hline \\ \text{C}_{I} \\ \hline \text{input capacitance, data and } \overline{\text{CSR}} \\ \hline \text{input capacitance,} \\ \hline \text{CK and } \overline{\text{CK}} \\ \hline \text{input switching at half clock} \\ \hline \text{frequency, 50 \% duty cycle.} \\ \hline \text{Io} = 0 \text{ mA; } V_{DD} = 1.8 \text{ V} \\ \hline \text{CK and } \overline{\text{CK}} \\ \hline \text{inputs} \\ \hline \text{input capacitance,} \\ \hline \text{CK and } \overline{\text{CK}} \\ \hline \text{inputs} \\ \hline \\ \hline \text{Input switching at half clock} \\ \hline \text{Switching at half clock} \\ \hline Switching at ha$	I _{DDD}		$V_I = V_{IH(AC)}$ or $V_{IL(AC)}$; CK and \overline{CK} switching at 50 % duty cycle.	-	16	-	μΑ
$V_{I} = V_{IH(AC)} \text{ or } V_{IL(AC)}; \text{ CK and } \overline{\text{CK}}$ switching at 50 % duty cycle. One data input switching at half clock frequency, 50 % duty cycle. $I_{O} = 0 \text{ mA}; V_{DD} = 1.8 \text{ V}$ $C_{i} \text{ input capacitance, data and } \overline{\text{CSR}} \text{ inputs}$ $V_{I} = V_{ref} \pm 250 \text{ mV}; V_{DD} = 1.8 \text{ V}$ $2.5 - 3.5 \text{ pF}$ inputs $V_{ICR} = 0.9 \text{ V}; V_{i(p-p)} = 600 \text{ mV}; \qquad 2 - 3 \text{ pF}$ $CK \text{ and } \overline{\text{CK}} \text{ inputs}$		· · · · · · · · · · · · · · · · · · ·	$V_I = V_{IH(AC)}$ or $V_{IL(AC)}$; CK and \overline{CK} switching at 50 % duty cycle. One data input switching at half clock frequency, 50 % duty cycle.	-	11	-	μА
inputs $ \begin{array}{lllllllllllllllllllllllllllllllllll$			$V_I = V_{IH(AC)}$ or $V_{IL(AC)}$; CK and \overline{CK} switching at 50 % duty cycle. One data input switching at half clock frequency, 50 % duty cycle.	-	19	-	μА
CK and $\overline{\text{CK}}$ inputs $V_{DD} = 1.8 \text{ V}$	Ci		$V_I = V_{ref} \pm 250 \text{ mV}; V_{DD} = 1.8 \text{ V}$	2.5	-	3.5	pF
input capacitance, \overline{RESET} input $V_I = V_{DD}$ or GND; $V_{DD} = 1.8 \text{ V}$ 3 - 4 pF		•		2	-	3	pF
		input capacitance, $\overline{\text{RESET}}$ input	$V_I = V_{DD}$ or GND; $V_{DD} = 1.8 \text{ V}$	3	-	4	pF

^[2] The differential inputs must not be floating, unless RESET is LOW.

Table 8: Timing requirements

At recommended operating conditions (see Table 6), unless otherwise specified. See Figure 2.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
f _{clock}	clock frequency		-	-	450	MHz
t _W	pulse duration, CK, $\overline{\text{CK}}$ HIGH or LOW		1	-	-	ns
t _{ACT}	differential inputs active time		[1][2]	-	10	ns
t _{INACT}	differential inputs inactive time		[1] [3]	-	15	ns
t _{su}	setup time	$\overline{\text{DCS}}$ before CK \uparrow , $\overline{\text{CK}}\downarrow$, $\overline{\text{CSR}}$ HIGH; $\overline{\text{CSR}}$ before CK \uparrow , $\overline{\text{CK}}\downarrow$, $\overline{\text{DCS}}$ HIGH	0.7	-	-	ns
		DCS before CK↑, CK↓, CSR LOW	0.5	-	-	ns
		DODT, DCKE and data (Dn) before CK \uparrow , $\overline{\text{CK}}\downarrow$	0.5	-	-	ns
		PAR_IN before CK↑, CK ↓	0.5	-	-	ns
t _h	hold time	DCS, DODT, DCKE and data (Dn) after CK↑, $\overline{\text{CK}} \downarrow$	0.5	-	-	ns
		PAR_IN after CK↑, CK↓	0.5	-	-	ns

^[1] This parameter is not necessarily production tested.

Table 9: Switching characteristics

At recommended operating conditions (see <u>Table 6</u>), unless otherwise specified. See <u>Section 11.1</u>.

$\begin{array}{cccccccccccccccccccccccccccccccccccc$	Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$\begin{array}{llllllllllllllllllllllllllllllllllll$	f_{MAX}	maximum input clock frequency		450	-	-	MHz
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	t_{PDM}	propagation delay, single bit switching	from CK \uparrow and $\overline{\text{CK}} \downarrow$ to Qn	<u>[1]</u> 1.41	-	1.8	ns
t_{HL} HIGH-to-LOW propagation delay from CK \uparrow and $\overline{CK}\downarrow$ to \overline{QERR} 1 - 2.4 t_{PDMSS} propagation delay, from CK \uparrow and $\overline{CK}\downarrow$ to \overline{QRR} 2.0	t_{PD}	propagation delay	from CK \uparrow and $\overline{\text{CK}} \downarrow$ to PPO	0.5	-	1.8	ns
t_{PDMSS} propagation delay, from CK \uparrow and $\overline{CK}\downarrow$ to Qn [1][2] 2.0	t_{LH}	LOW-to-HIGH propagation delay	from CK \uparrow and $\overline{\text{CK}} \downarrow$ to $\overline{\text{QERR}}$	1.2	-	3	ns
1 Divide 1 1 1 3 th 1 1 1 1	t_{HL}	HIGH-to-LOW propagation delay	from CK↑ and $\overline{\text{CK}}$ to $\overline{\text{QERR}}$	1	-	2.4	ns
simulaneous switching	t _{PDMSS}	propagation delay, simultaneous switching	from CK \uparrow and $\overline{\text{CK}} \downarrow$ to Qn	[1][2] _	-	2.0	ns
t_{PHL} HIGH-to-LOW propagation delay from $\overline{\text{RESET}} \downarrow$ to $\text{Qn} \downarrow$ 3	t _{PHL}	HIGH-to-LOW propagation delay	from RESET↓ to Qn↓	-	-	3	ns
from $\overline{RESET} \downarrow$ to $PPO \downarrow$ 3			from $\overline{RESET} \downarrow$ to $PPO \downarrow$	-	-	3	ns
t_{PLH} LOW-to-HIGH propagation delay from \overline{RESET} to \overline{QERR} 3	t _{PLH}	LOW-to-HIGH propagation delay	from RESET↓ to QERR↑	-	-	3	ns

^[1] Includes 350 ps of test-load transmission line delay.

Table 10: Data output edge rates

At recommended operating conditions (see <u>Table 6</u>), unless otherwise specified. See <u>Section 11.2</u>.

		-				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
dV/dt_r	rising edge slew rate	from 20 % to 80 %	1	-	4	V/ns
dV/dt_f	falling edge slew rate	from 80 % to 20 %	1	-	4	V/ns
dV/dt_Δ	absolute difference between dV/dt_r and dV/dt_f	from 20 % or 80 % to 80 % or 20 %	-	-	1	V/ns

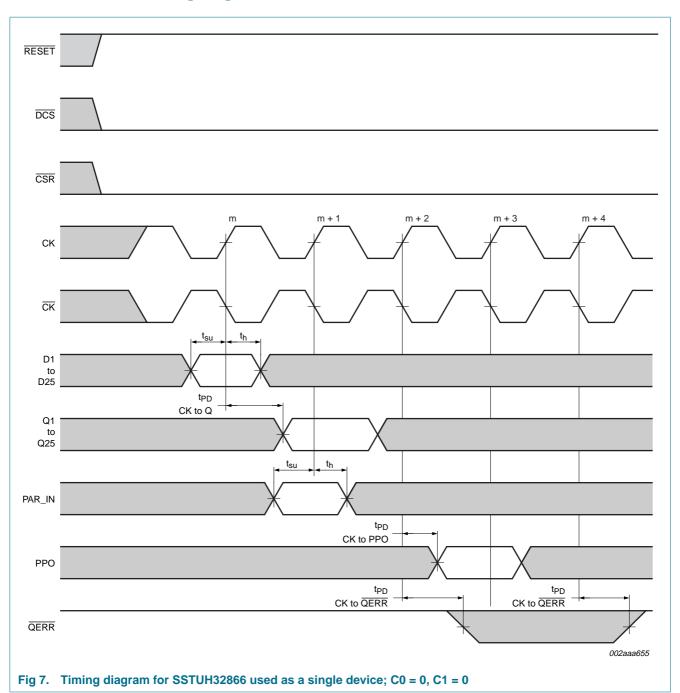
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^[2] VREF must be held at a valid input voltage level and data inputs must be held LOW for a minimum time of t_{ACT(max)} after RESET is taken HIGH.

^[3] VREF, data and clock inputs must be held at valid levels (not floating) a minimum time of t_{INACT(max)} after RESET is taken LOW.

^[2] This parameter is not necessarily production tested.

10.1 Timing diagrams



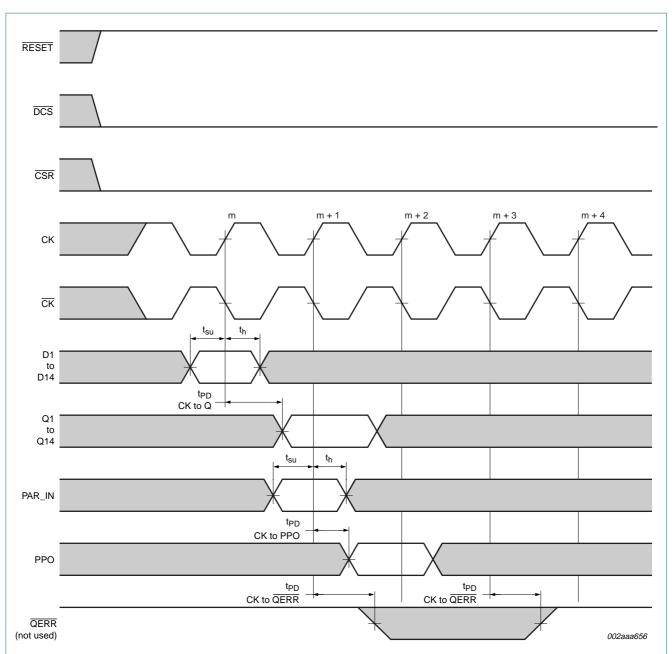
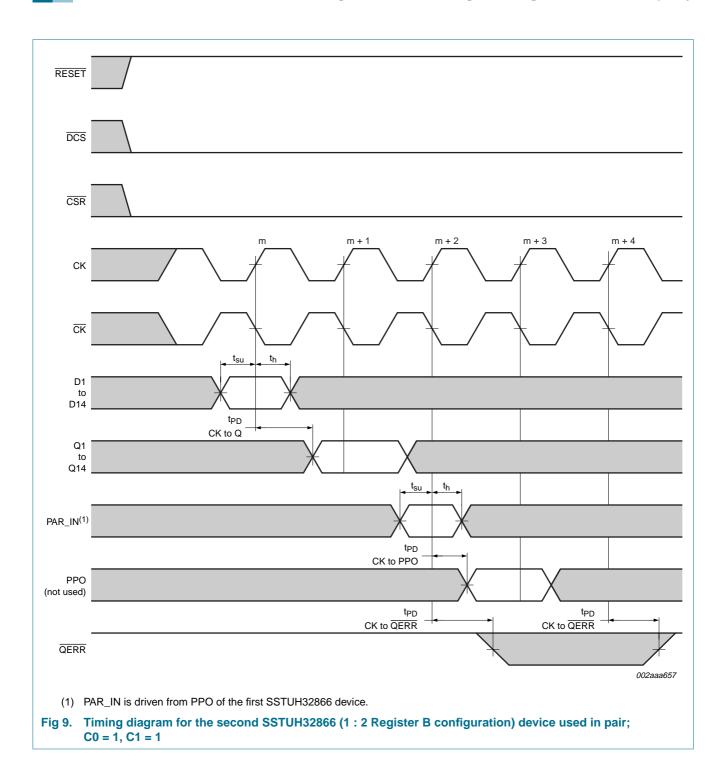


Fig 8. Timing diagram for the first SSTUH32866 (1 : 2 Register A configuration) device used in pair; C0 = 0, C1 = 1



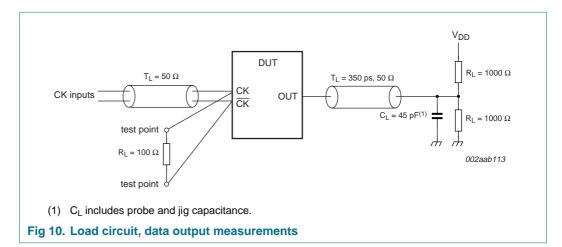
11. Test information

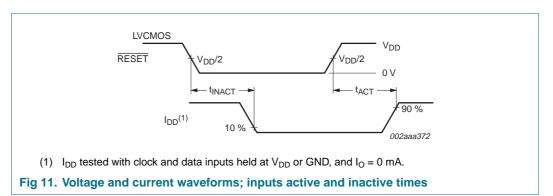
11.1 Parameter measurement information for data output load circuit

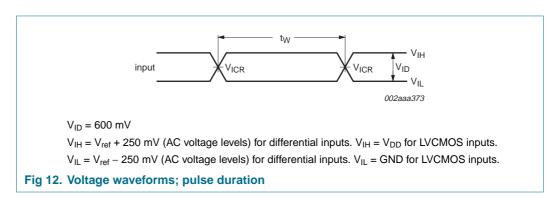
 $V_{DD} = 1.8 \text{ V} \pm 0.1 \text{ V}.$

All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz; $Z_0 = 50 \Omega$; input slew rate = 1 V/ns \pm 20 %, unless otherwise specified.

The outputs are measured one at a time with one transition per measurement.







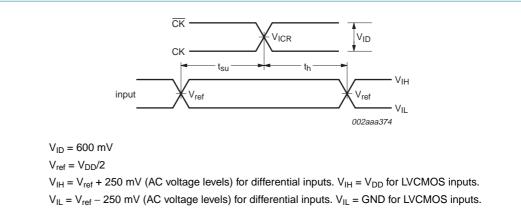


Fig 13. Voltage waveforms; setup and hold times

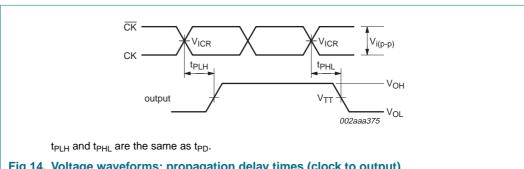
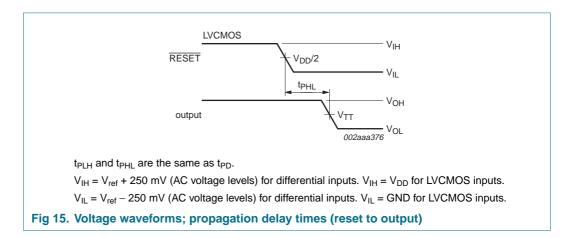


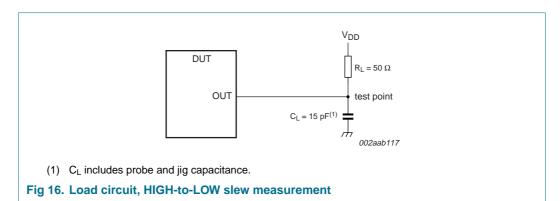
Fig 14. Voltage waveforms; propagation delay times (clock to output)

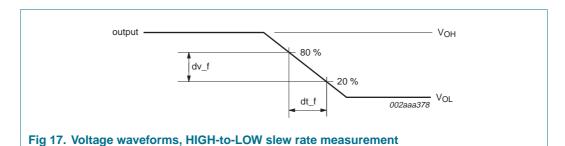


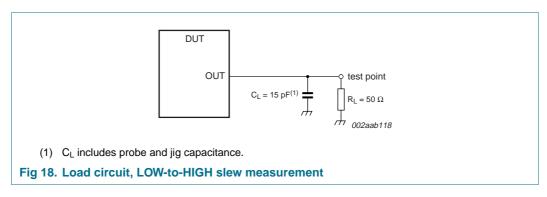
11.2 Data output slew rate measurement information

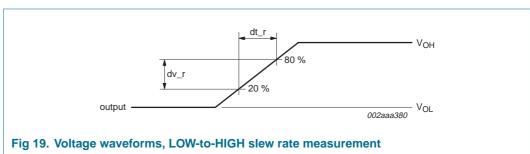
 $V_{DD} = 1.8 \text{ V} \pm 0.1 \text{ V}.$

All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz; Z_0 = 50 Ω ; input slew rate = 1 V/ns \pm 20 %, unless otherwise specified.





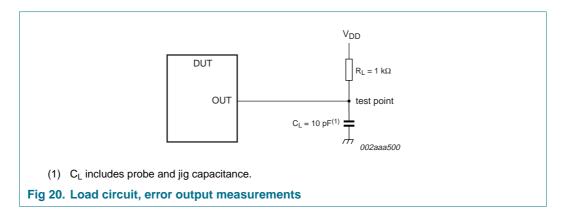




11.3 Error output load circuit and voltage measurement information

 $V_{DD} = 1.8 \text{ V} \pm 0.1 \text{ V}.$

All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz; $Z_0 = 50 \Omega$; input slew rate = 1 V/ns \pm 20 %, unless otherwise specified.



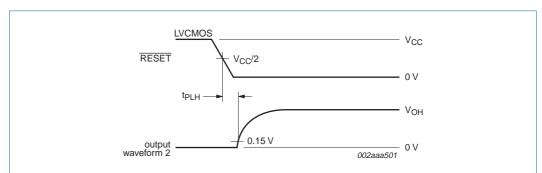


Fig 21. Voltage waveforms, open-drain output LOW-to-HIGH transition time with respect to RESET input.

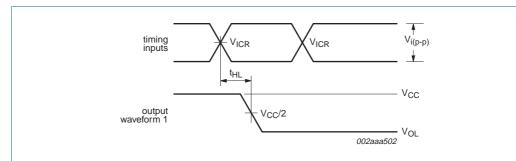


Fig 22. Voltage waveforms, open-drain output HIGH-to-LOW transition time with respect to clock inputs

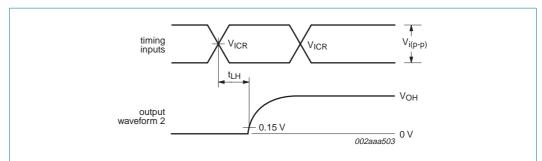
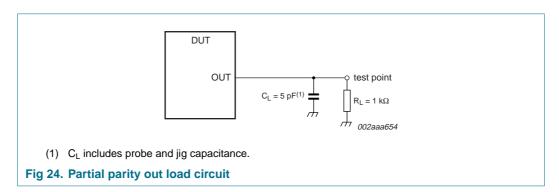


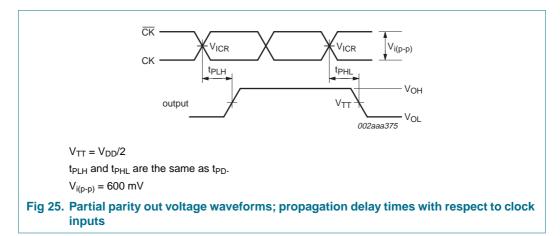
Fig 23. Voltage waveforms, open-drain output LOW-to-HIGH transition time with respect to clock inputs

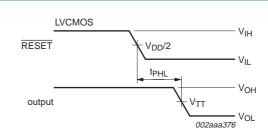
11.4 Partial parity out load circuit and voltage measurement information

 $V_{DD} = 1.8 \text{ V} \pm 0.1 \text{ V}.$

All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz; $Z_0 = 50 \Omega$; input slew rate = 1 V/ns \pm 20 %, unless otherwise specified.







 $V_{TT} = V_{DD}/2$

 t_{PLH} and t_{PHL} are the same as t_{PD} .

 V_{IH} = V_{ref} + 250 mV (AC voltage levels) for differential inputs. V_{IH} = V_{DD} for LVCMOS inputs.

 V_{IL} = V_{ref} – 250 mV (AC voltage levels) for differential inputs. V_{IL} = V_{DD} for LVCMOS inputs.

Fig 26. Partial parity out voltage waveforms; propagation delay times with respect to RESET input

12. Package outline

LFBGA96: plastic low profile fine-pitch ball grid array package; 96 balls; body 13.5 x 5.5 x 1.05 mm SOT536-1

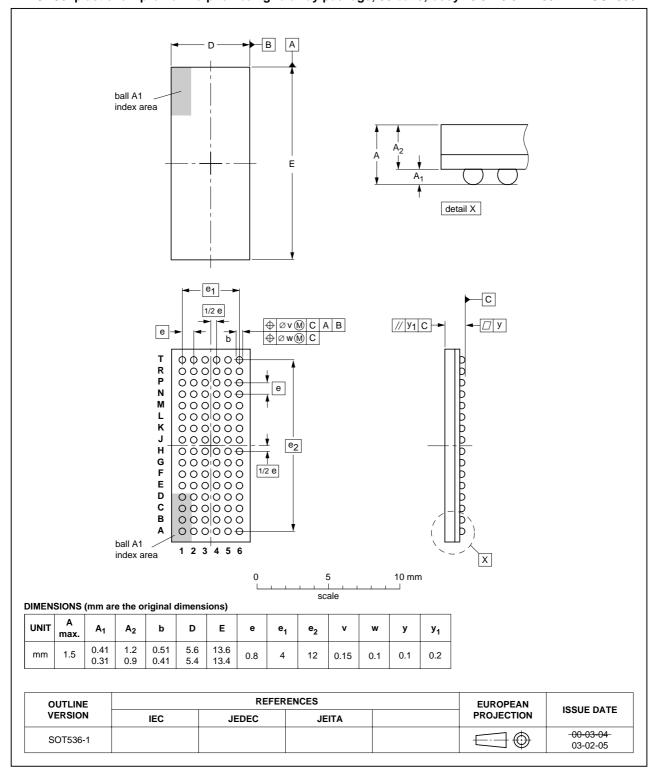


Fig 27. Package outline SOT536-1 (LFBGA96)

Product data sheet

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13. Soldering

13.1 Introduction to soldering surface mount packages

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *Data Handbook IC26; Integrated Circuit Packages* (document order number 9398 652 90011).

There is no soldering method that is ideal for all surface mount IC packages. Wave soldering can still be used for certain surface mount ICs, but it is not suitable for fine pitch SMDs. In these situations reflow soldering is recommended.

13.2 Reflow soldering

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement. Driven by legislation and environmental forces the worldwide use of lead-free solder pastes is increasing.

Several methods exist for reflowing; for example, convection or convection/infrared heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 seconds and 200 seconds depending on heating method.

Typical reflow peak temperatures range from 215 °C to 270 °C depending on solder paste material. The top-surface temperature of the packages should preferably be kept:

- below 225 °C (SnPb process) or below 245 °C (Pb-free process)
 - for all BGA, HTSSON..T and SSOP..T packages
 - for packages with a thickness ≥ 2.5 mm
 - for packages with a thickness < 2.5 mm and a volume ≥ 350 mm³ so called thick/large packages.
- below 240 °C (SnPb process) or below 260 °C (Pb-free process) for packages with a thickness < 2.5 mm and a volume < 350 mm³ so called small/thin packages.

Moisture sensitivity precautions, as indicated on packing, must be respected at all times.

13.3 Wave soldering

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
 - larger than or equal to 1.27 mm, the footprint longitudinal axis is preferred to be parallel to the transport direction of the printed-circuit board;

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 smaller than 1.27 mm, the footprint longitudinal axis must be parallel to the transport direction of the printed-circuit board.

The footprint must incorporate solder thieves at the downstream end.

• For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time of the leads in the wave ranges from 3 seconds to 4 seconds at 250 °C or 265 °C, depending on solder material applied, SnPb or Pb-free respectively.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

13.4 Manual soldering

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to $300\,^{\circ}$ C.

When using a dedicated tool, all other leads can be soldered in one operation within 2 seconds to 5 seconds between 270 °C and 320 °C.

13.5 Package related soldering information

Table 11: Suitability of surface mount IC packages for wave and reflow soldering methods

Package [1]	Soldering method		
	Wave	Reflow [2]	
BGA, HTSSONT 3, LBGA, LFBGA, SQFP, SSOPT 3, TFBGA, VFBGA, XSON	not suitable	suitable	
DHVQFN, HBCC, HBGA, HLQFP, HSO, HSOP, HSQFP, HSSON, HTQFP, HTSSOP, HVQFN, HVSON, SMS	not suitable [4]	suitable	
PLCC [5], SO, SOJ	suitable	suitable	
LQFP, QFP, TQFP	not recommended [5] [6]	suitable	
SSOP, TSSOP, VSO, VSSOP	not recommended [7]	suitable	
CWQCCNL[8], PMFP[9], WQCCNL[8]	not suitable	not suitable	

For more detailed information on the BGA packages refer to the (LF)BGA Application Note (AN01026);
 order a copy from your Philips Semiconductors sales office.

Product data sheet

^[2] All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods.

^[3] These transparent plastic packages are extremely sensitive to reflow soldering conditions and must on no account be processed through more than one soldering cycle or subjected to infrared reflow soldering with peak temperature exceeding 217 °C ± 10 °C measured in the atmosphere of the reflow oven. The package body peak temperature must be kept as low as possible.

Philips Semiconductors SSTUH32866

1.8 V high-drive DDR2 configurable registered buffer with parity

- [4] These packages are not suitable for wave soldering. On versions with the heatsink on the bottom side, the solder cannot penetrate between the printed-circuit board and the heatsink. On versions with the heatsink on the top side, the solder might be deposited on the heatsink surface.
- [5] If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
- [6] Wave soldering is suitable for LQFP, QFP and TQFP packages with a pitch (e) larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
- [7] Wave soldering is suitable for SSOP, TSSOP, VSO and VSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.
- [8] Image sensor packages in principle should not be soldered. They are mounted in sockets or delivered pre-mounted on flex foil. However, the image sensor package can be mounted by the client on a flex foil by using a hot bar soldering process. The appropriate soldering profile can be provided on request.
- [9] Hot bar soldering or manual soldering is suitable for PMFP packages.

14. Abbreviations

Table 12: Abbreviations

Description
Complementary Metal Oxide Silicon
Double Data Rate
Dual In-line Memory Module
Dynamic Random Access Memory
Joint Electron Device Engineering Council
Low profile Fine-pitch Ball Grid Array
Low Voltage Complementary Metal Oxide Silicon
Partial Parity Out
Pulse Repetition Rate
Registered Dual In-line Memory Module
Stub Series Terminated Logic
([[[

15. Revision history

Table 13: Revision history

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
SSTUH32866_1	20050513	Product data sheet	-	9397 750 14199	-

16. Data sheet status

Level	Data sheet status [1]	Product status [2] [3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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SSTUH32866

1.8 V high-drive DDR2 configurable registered buffer with parity

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